CMOS High Frequency/Low Voltage Full-Wave Rectifier

Adisak Monpapassorn

Department of Electronic Engineering, South-East Asia University,

Bangkok 10160, Thailand

Abstract

A CMOS high frequency/low voltage full-wave rectifier is presented. The proposed rectifier is composed of three main components: a dual output V-I converter, a positive full/wave current rectifier, and an I-V converter. A voltage input signal is changed into two out-of phase current signals by the V-I converter. The current rectifier rectifies these current signals resulting in a positive full-wave current output signal that is finally changed into a positive full-wave voltage output signal by the I-V converter. The theory of operation is described, and the simulation results obtained from the PSPICE program are used to verify the theoretical prediction. Simulation rectifier performance with a 0.5 μ m MOS model obtained through MIETEC, using a \pm 1.2 V supply voltage, demonstrates good rectifier integrity at operation frequencies up to 100 MHz

Keywords:	 , .	 	,	